Substitute form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application Number	~~To Be Assigned~~ 10/780,067
				Filing Date	Concurrently Herewith
				First Named Inventor	Tai-su Park et al,
				Group Art Unit	N/A
(use as many sheets as necessary)				Examiner Name	
Sheet	1	of	1	Attorney Docket Number	5649-1192

U.S. PATENTS AND PATENT PUBLICATIONS					
Examiner Initials*	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
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MP	1	US-6,355,532	—	Seliskar et al.	03/12/2002

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		Office	Number	Kind Code (if known)			

OTHER NON PATENT LITERATURE DOCUMENTS			
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MP	2	Fu-Liang Yang, et al., "2002 Symposium in VLSI Technology Digest of Technical Power," IEEE, 2002	
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Examiner Signature		Date Considered	9/05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.